



## UMX4214

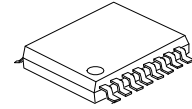
CMOS IC

### 4.5Ω, LOW VOLTAGE QUAD, HIGH SPEED, SPDT ANALOG SWITCH

#### DESCRIPTION

The UTC **UMX4214** is a quad, SPDT (single-pole/double-throw), TTL/CMOS compatible analog switch. It operates from a 1.8V to 5.5V single power supply.

The UTC **UMX4214** features high-speed, low on-resistance, low voltage and high bandwidth. The high performances make it very suitable for multiple applications, such as portable equipment, audio and video signal routing, etc. Low power consumption is also one of the important reasons that make it a good choice.



TSSOP-16

#### FEATURES

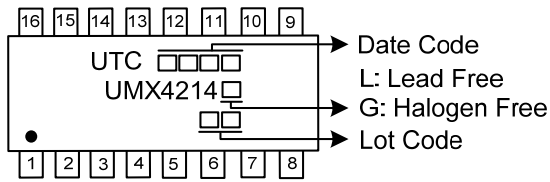
- \* Single Supply Voltage Range: 1.8V ~ 5.5V
- \* Low On-Resistance: 4.5Ω (TYP)
- \* Rail-to-Rail Input and Output Operation
- \* TTL/CMOS Compatible
- \* Low On-Resistance Flatness
- \* Fast Switching Times:
  - ton: 25ns
  - toff: 25ns
- \* Low Power Consumption

#### ORDERING INFORMATION

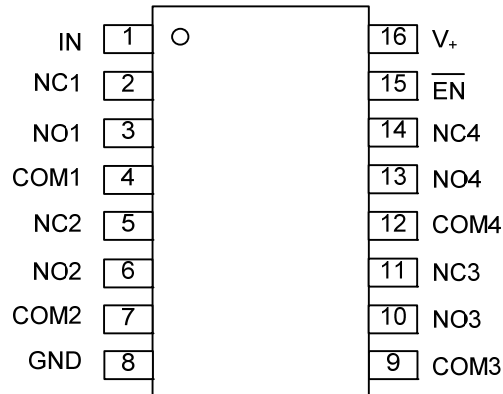
Ordering Number		Package	Packing
Lead Free	Halogen Free		
UMX4214L-P16-R	UMX4214G-P16-R	TSSOP-16	Tape Reel

<p>UMX4214G-P16-R</p> <ul style="list-style-type: none"> <li>(1) Packing Type</li> <li>(2) Package Type</li> <li>(3) Green Package</li> </ul>	<ul style="list-style-type: none"> <li>(1) R: Tape Reel</li> <li>(2) P16: TSSOP-16</li> <li>(3) G: Halogen Free and Lead Free, L: Lead Free</li> </ul>
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## MARKING



## PIN CONFIGURATION



## PIN DESCRIPTION

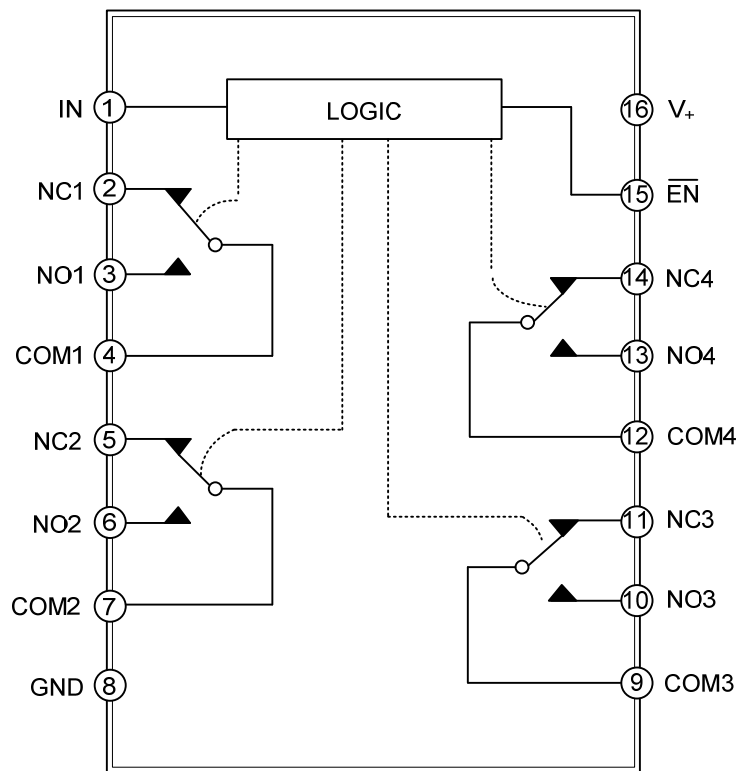
PIN NO.	PIN NAME	DESCRIPTION
1	IN	Digital Control Input Pin to Connect the COM Pins to the NO or NC Pins.
2, 5, 11, 14	NCx	Normally Closed Pins.
3, 6, 10, 13	NOx	Normally Open Pins.
4, 7, 9, 12	COMx	Common Pins.
8	GND	Ground.
15	$\overline{EN}$	Digital Enable Control. Normally connect to GND. Drive to logic high to set all switches off.
16	V+	Positive Power Supply.

## FUNCTION TABLE

$\overline{EN}$	IN	NO	NC
L	L	OFF	ON
L	H	ON	OFF
H	√	All Switches Open	

Note: √ = Don't Care.

■ BLOCK DIAGRAM



■ **ABSOLUTE MAXIMUM RATING**

PARAMETER	SYMBOL	RATINGS	UNIT
V <sub>+</sub> to GND		-0.3 ~ 6	V
Analog, Digital Voltage Range (Note 1)		-0.3 ~ (V <sub>+</sub> ) + 0.3	V
Continuous Current NO, NC, or COM		±100	mA
Junction Temperature	T <sub>J</sub>	+150	°C
Storage Temperature Range	T <sub>STG</sub>	-65 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.  
 2. Signals on NC, NO, or COM or INX exceeding V<sub>+</sub> will be clamped by internal diodes. Limit forward diode current to maximum current ratings.

■ **RECOMMENDED OPERATING CONDITIONS**

PARAMETER	SYMBOL	RATINGS	UNIT
Operating Temperature Range	T <sub>A</sub>	-40 ~ +85	°C

## ■ ELECTRICAL CHARACTERISTICS

( $V_+ = 4.5V \sim 5.5V$ ,  $GND = 0V$ ,  $V_{IH} = 1.6V$ ,  $V_{IL} = 0.5V$ , Full =  $-40^\circ C \sim +85^\circ C$ . Typical values are at  $V_+ = 5V$ ,  $T_A = +25^\circ C$ , unless otherwise specified)

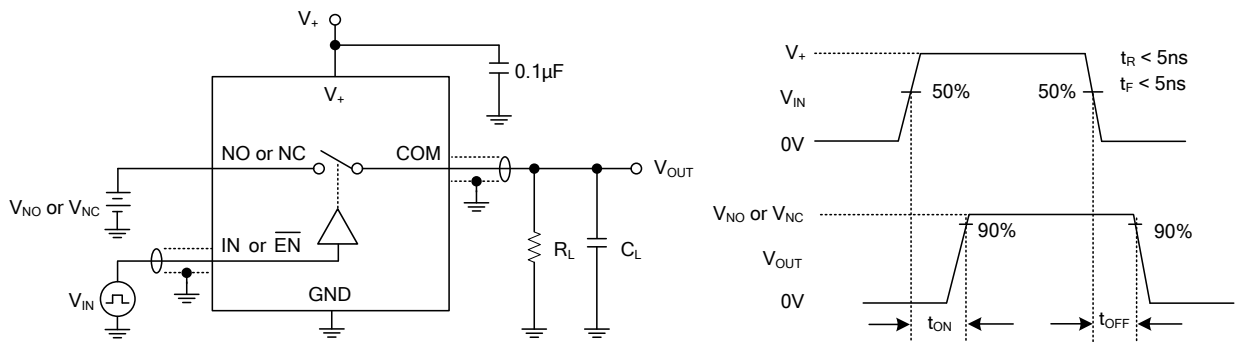
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>ANALOG SWITCH</b>						
Analog Signal Range	$V_{NO}, V_{NC}, V_{COM}$	$T_A = -40 \sim +85^\circ C$	0		$V_+$	V
On-Resistance	$R_{ON}$	$V_+ = 4.5V, V_{NO}$ or $V_{NC} = 1.2V, I_{COM} = -100mA$	$T_A = +25^\circ C$	4.5	7	$\Omega$
			$T_A = -40 \sim +85^\circ C$		8	$\Omega$
On-Resistance Match Between Channels	$\Delta R_{ON}$	$V_+ = 4.5V, V_{NO}$ or $V_{NC} = 1.2V, I_{COM} = -100mA$	$T_A = +25^\circ C$	0.8	3.6	$\Omega$
			$T_A = -40 \sim +85^\circ C$		4.2	$\Omega$
On-Resistance Flatness	$R_{FLAT(ON)}$	$V_+ = 4.5V, V_{NO}$ or $V_{NC} = 1.2V, 4.5V, I_{COM} = -100mA$	$T_A = +25^\circ C$	3	3.7	$\Omega$
			$T_A = -40 \sim +85^\circ C$		4.5	$\Omega$
Source Off Leakage Current	$I_{NC(OFF)}, I_{NO(OFF)}$	$V_+ = 5.5V, V_{NO}$ or $V_{NC} = 3.3V/0.3V, V_{COM} = 0.3V/3.3V, T_A = -40 \sim +85^\circ C$			1	$\mu A$
Channel On Leakage Current	$I_{NC(ON)}, I_{NO(ON)}, I_{COM(ON)}$	$V_+ = 5.5V, V_{COM} = 0.3V/3.3V, V_{NO}$ or $V_{NC} = 0.3V/3.3V$ , or floating, $T_A = -40 \sim +85^\circ C$			1	$\mu A$
<b>DIGITAL INPUTS</b>						
Input High Voltage	$V_{INH}$	$T_A = -40 \sim +85^\circ C$	1.6			V
Input Low Voltage	$V_{INL}$	$T_A = -40 \sim +85^\circ C$			0.5	V
Input Leakage Current	$I_{IN}$	$V_+ = 5.5V, V_{IN} = 0V$ or $5.5V, T_A = -40 \sim +85^\circ C$			1	$\mu A$
<b>DYNAMIC CHARACTERISTICS</b>						
Turn-On Time	$t_{ON}$	$V_{NO}$ or $V_{NC} = 2V, C_L = 35pF, R_L = 300\Omega,$		25		ns
Turn-Off Time	$t_{OFF}$	Test Circuit 1, $T_A = +25^\circ C$		22		ns
Charge Injection Select Input to Common I/O	Q	$V_G = GND, R_G = 0\Omega, Q = C_L \times V_{OUT}, C_L = 1nF$ , Test Circuit 2, $T_A = +25^\circ C$		20		pC
Break-Before-Make Time Delay	$t_D$	$V_{NO}$ or $V_{NC} = 3V, R_L = 300\Omega, C_L = 35pF,$ Test Circuit 3, $T_A = +25^\circ C$		18		ns
Off Isolation	$O_{ISO}$	$R_L = 50\Omega, f = 10MHz, V_{BIAS} = 350mV, Signal = 0dBm,$ Test Circuit 4, $T_A = +25^\circ C$	1MHz	-70		dB
			10MHz	-50		dB
Channel-to-Channel Crosstalk	$X_{TALK}$	$R_L = 50\Omega, f = 10MHz, V_{BIAS} = 350mV, Signal = 0dBm,$ Test Circuit 5, $T_A = +25^\circ C$	1MHz	-90		dB
			10MHz	-60		dB
-3dB Bandwidth	BW	$R_L = 50\Omega, Signal = 0dBm, V_{BIAS} = 350mV,$ Test Circuit 6, $T_A = +25^\circ C$		300		MHz
Channel On Capacitance	$C_{ON}$	$T_A = +25^\circ C$		42		pF
<b>POWER REQUIREMENTS</b>						
Power Supply Range	$V_+$	$T_A = -40 \sim +85^\circ C$	1.8		5.5	V
Power Supply Current	$I_+$	$V_+ = 5.5V, V_{IN} = 0V$ or $V_+, T_A = -40 \sim +85^\circ C$			1	$\mu A$

## ■ ELECTRICAL CHARACTERISTICS

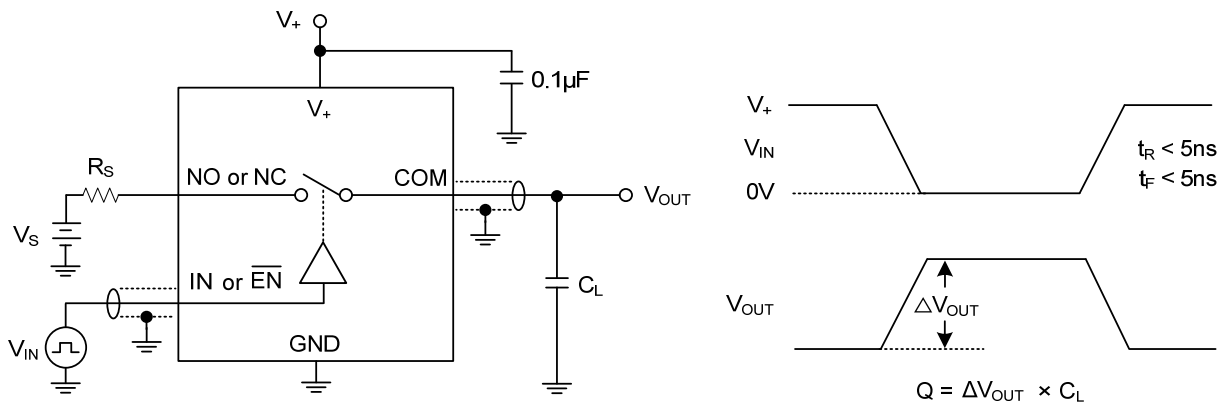
( $V_+ = 2.7V \sim 3.6V$ ,  $V_{IH} = 1.6V$ ,  $V_{IL} = 0.4V$ , Full =  $-40^\circ C \sim +85^\circ C$ . Typical values are at  $V_+ = 3V$ ,  $T_A = +25^\circ C$ , unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>ANALOG SWITCH</b>						
Analog Signal Range	$V_{NO}, V_{NC}, V_{COM}$	$T_A = -40 \sim +85^\circ C$	0		$V_+$	V
On-Resistance	$R_{ON}$	$V_+ = 2.7V, V_{NO} \text{ or } V_{NC} = 1.2V, I_{COM} = -100mA$	$T_A = +25^\circ C$	8	15.5	$\Omega$
			$T_A = -40 \sim +85^\circ C$		18.5	$\Omega$
On-Resistance Match Between Channels	$\Delta R_{ON}$	$V_+ = 2.7V, V_{NO} \text{ or } V_{NC} = 1.2V, I_{COM} = -100mA$	$T_A = +25^\circ C$	1.6	4	$\Omega$
			$T_A = -40 \sim +85^\circ C$		4.6	$\Omega$
On-Resistance Flatness	$R_{FLAT(ON)}$	$V_+ = 2.7V, V_{NO} \text{ or } V_{NC} = 1.2V, 4.5V, I_{COM} = -100mA$	$T_A = +25^\circ C$	7	9.4	$\Omega$
			$T_A = -40 \sim +85^\circ C$		13	$\Omega$
Source Off Leakage Current	$I_{NC(OFF)}, I_{NO(OFF)}$	$V_+ = 3.6V, V_{NO} \text{ or } V_{NC} = 3.3V/0.3V, V_{COM} = 0.3V/3.3V, T_A = -40 \sim +85^\circ C$			1	$\mu A$
Channel On Leakage Current	$I_{NC(ON)}, I_{NO(ON)}, I_{COM(ON)}$	$V_+ = 3.6V, V_{COM} = 0.3V/3.3V, V_{NO} \text{ or } V_{NC} = 0.3V/3.3V, \text{ or floating}, T_A = -40 \sim +85^\circ C$			1	$\mu A$
<b>DIGITAL INPUTS</b>						
Input High Voltage	$V_{INH}$	$T_A = -40 \sim +85^\circ C$	1.5			V
Input Low Voltage	$V_{INL}$	$T_A = -40 \sim +85^\circ C$			0.4	V
Input Leakage Current	$I_{IN}$	$V_+ = 5.5V, V_{IN} = 0V \text{ or } 3.6V, T_A = -40 \sim +85^\circ C$			1	$\mu A$
<b>DYNAMIC CHARACTERISTICS</b>						
Turn-On Time	$t_{ON}$	$V_{NO} \text{ or } V_{NC} = 2V, C_L = 35pF, R_L = 300\Omega,$		38		ns
Turn-Off Time	$t_{OFF}$	Test Circuit 1, $T_A = +25^\circ C$		55		ns
Charge Injection Select Input to Common I/O	Q	$V_G = GND, R_G = 0\Omega, Q = C_L \times V_{OUT}, C_L = 1nF, \text{ Test Circuit 2}, T_A = +25^\circ C$		20		pC
Break-Before-Make Time Delay	$t_D$	$V_{NO} \text{ or } V_{NC} = 2V, R_L = 300\Omega, C_L = 35pF, \text{ Test Circuit 3}, T_A = +25^\circ C$		20		ns
Off Isolation	$O_{ISO}$	$R_L = 50\Omega, f = 10MHz, V_{BIAS} = 350mV, \text{ Signal} = 0dBm, \text{ Test Circuit 4}, T_A = +25^\circ C$	1MHz	-70		dB
			10MHz	-50		dB
Channel-to-Channel Crosstalk	$X_{TALK}$	$R_L = 50\Omega, f = 10MHz, V_{BIAS} = 350mV, \text{ Signal} = 0dBm, \text{ Test Circuit 5}, T_A = +25^\circ C$	1MHz	-90		dB
			10MHz	-60		dB
-3dB Bandwidth	BW	$R_L = 50\Omega, \text{ Signal} = 0dBm, V_{BIAS} = 350mV, \text{ Test Circuit 6}, T_A = +25^\circ C$		300		MHz
Channel On Capacitance	$C_{ON}$	$T_A = +25^\circ C$		42		pF

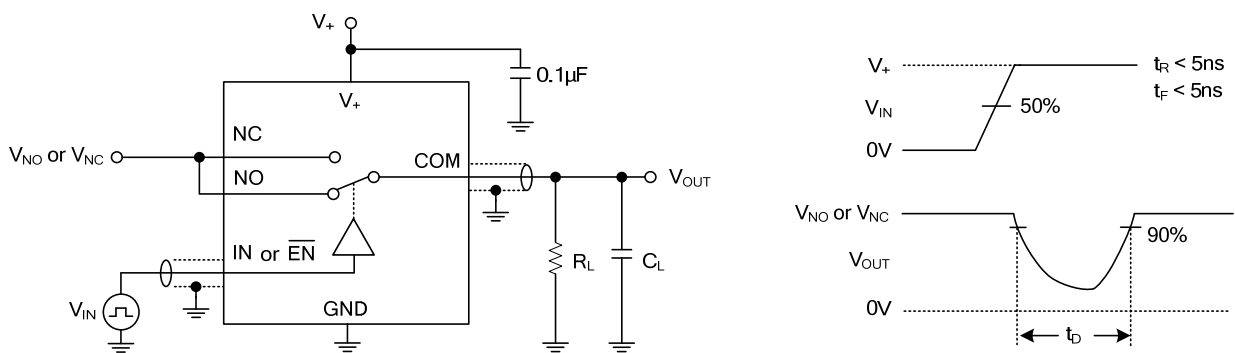
## ■ TEST CIRCUIT



Test Circuit 1. Switching Times

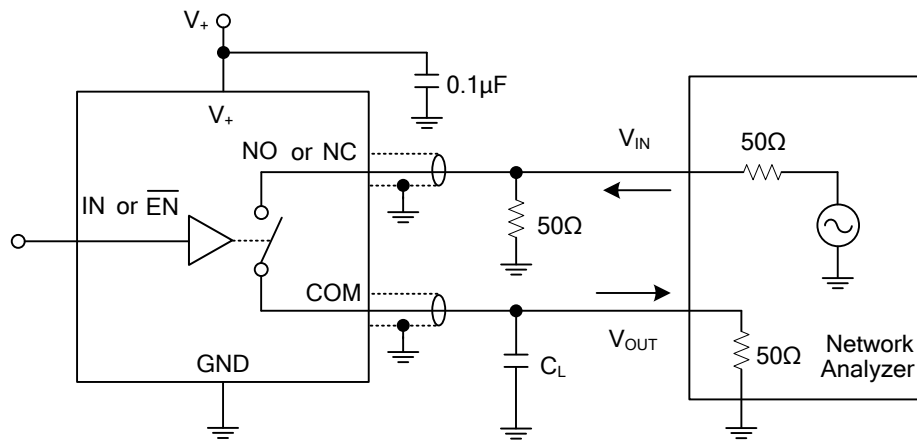


Test Circuit 2. Charge Injection

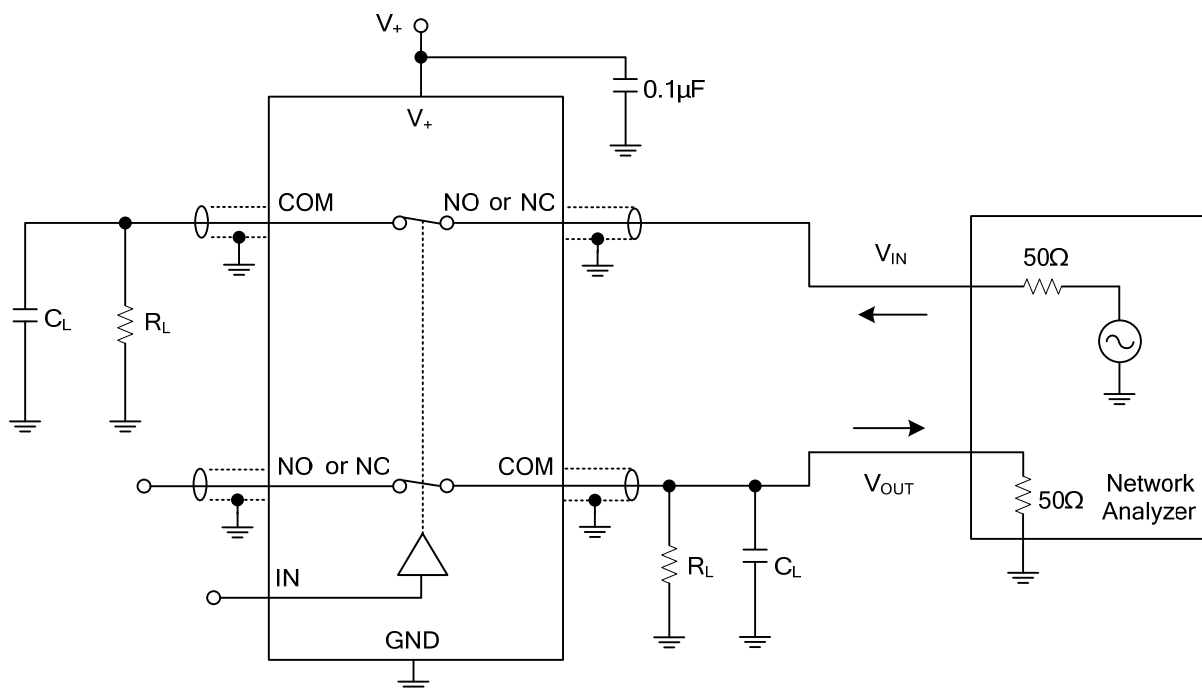


Test Circuit 3. Break-Before-Make Time Delay,  $t_D$

■ TEST CIRCUIT



Test Circuit 4. Off Isolation

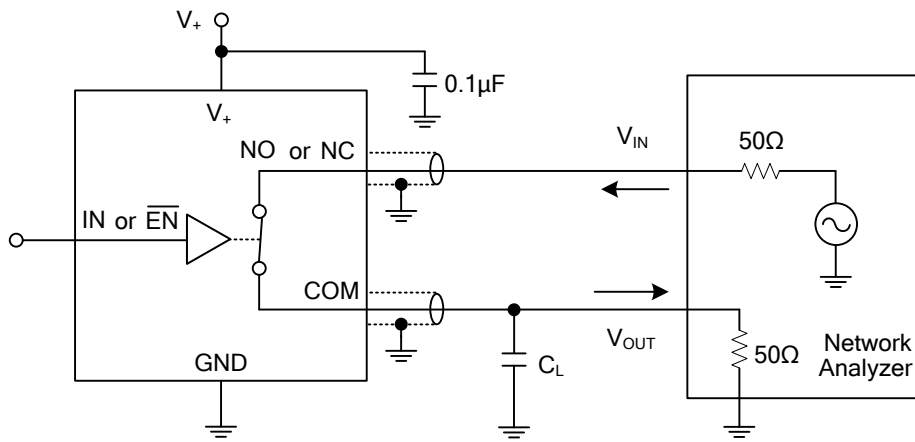


$$\text{Channel-to-Channel Crosstalk} = -20 \log (V_{NO} \text{ or } V_{NC}/V_{OUT})$$

Test Circuit 5. Channel-to-Channel Crosstalk

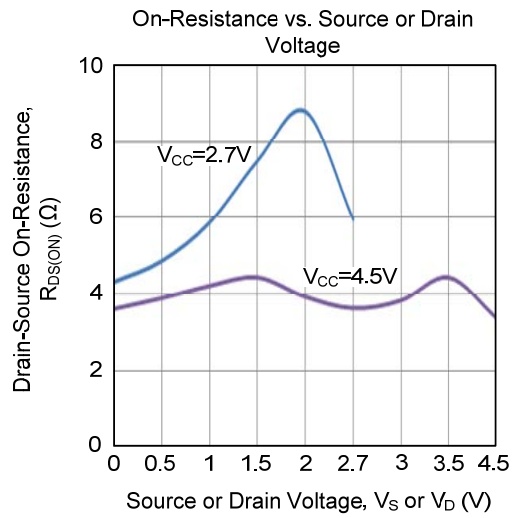


■ TEST CIRCUIT



Test Circuit 6. -3dB Bandwidth

■ TYPICAL CHARACTERISTICS



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